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## PN3645

### Silicon PNP Transistor

### Audio Amplifier, Switch

### TO-92 Type Package

**Absolute Maximum Ratings:** ( $T_A = +25^\circ\text{C}$ , Note 1 unless otherwise specified)

Collector-Emitter Voltage, $V_{CEO}$ .....	60V
Collector-Base Voltage, $V_{CBO}$ .....	60V
Emitter-Base Voltage, $V_{EBO}$ .....	5V
Continuous Collector Current, $I_C$ .....	800mA
Total Device Dissipation ( $T_A = 25^\circ\text{C}$ ), $P_D$ .....	625mW
Derate Above $25^\circ\text{C}$ .....	5mW/ $^\circ\text{C}$
Operating Junction Temperature Range, $T_J$ .....	-55° to +150°C
Storage Temperature Range, $T_{stg}$ .....	-55° to +150°C
Thermal Resistance, Junction to Case, $R_{\theta JC}$ .....	83.3°C/W
Thermal Resistance, Junction to Ambient, $R_{\theta JA}$ .....	200°C/W

Note 1. These ratings are limiting values above which the serviceability of any semiconductor device may be impaired and are based on a maximum junction temperature of +150°C.

**Electrical Characteristics:** ( $T_A = +25^\circ\text{C}$  unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
<b>OFF Characteristics</b>						
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 10\text{mA}$ , $I_B = 0$ , Note 2	60	-	-	V
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = 100\mu\text{A}$ , $I_E = 0$	60	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = 10\mu\text{A}$ , $I_C = 0$	5	-	-	V
Collector Cutoff Current	$I_{CES}$	$V_{CB} = 50\text{V}$ , $I_E = 0$	-	-	35	nA
		$V_{CB} = 50\text{V}$ , $I_E = 0$ , $T_A = +65^\circ\text{C}$	-	-	2	$\mu\text{A}$
Base Cutoff Current	$I_{BL}$	$V_{CE} = 50\text{V}$ , $I_C = 0$	-	-	35	nA
<b>ON Characteristics (Note 2)</b>						
DC Current Gain	$h_{FE}$	$V_{CE} = 10\text{V}$ , $I_C = 0.1\text{mA}$	40	-	-	
		$V_{CE} = 10\text{V}$ , $I_C = 1\text{mA}$	80	-	-	
		$V_{CE} = 10\text{V}$ , $I_C = 10\text{mA}$	100	-	-	
		$V_{CE} = 10\text{V}$ , $I_C = 150\text{mA}$	100	-	300	
		$V_{CE} = 2\text{V}$ , $I_C = 300\text{mA}$	20	-	-	
		$V_{CE} = 1\text{V}$ , $I_C = 50\text{mA}$	80	-	240	
Collector-Emitter Saturation Voltage	$V_{CE(\text{sat})}$	$I_C = 50\text{mA}$ , $I_B = 2.5\text{mA}$	-	-	0.25	V
		$I_C = 150\text{mA}$ , $I_B = 15\text{mA}$	-	-	0.4	V

Note 2. Pulse Test: Pulse Width  $\leq 300\mu\text{s}$ , Duty Cycle  $\leq 2\%$ .

**Electrical Characteristics (Cont'd):** ( $T_A = +25^\circ\text{C}$  unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
<b>ON Characteristics (Cont'd) (Note 2)</b>						
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = 50\text{mA}, I_B = 2.5\text{mA}$	-	-	1.0	V
		$I_C = 150\text{mA}, I_B = 15\text{mA}$	-	-	1.3	V
<b>Small Signal Characteristics</b>						
Output Capacitance	$C_{ob}$	$V_{CB} = 10\text{V}, f = 140\text{kHz}$	-	-	8	pF
Input Capacitance	$C_{ib}$	$V_{BE} = 0.5\text{V}, f = 140\text{kHz}$	-	-	35	pF
Small-Signal Current Gain	$h_{fe}$	$I_C = 20\text{mA}, V_{CE} = 20\text{V}, f = 100\text{MHz}$	2.0	-	-	
<b>Switching Characteristics</b>						
Turn-On Time	$t_{on}$	$V_{CC} = 30\text{V}, I_C = 300\text{mA}, I_{B1} = 30\text{mA}$	-	-	40	ns
Delay Time	$t_d$		-	-	25	ns
Rise Time	$t_r$		-	-	35	ns
Turn-Off Time	$t_{off}$	$V_{CC} = 30\text{V}, I_C = 300\text{mA}, I_{B1} = I_{B2} = 30\text{mA}$	-	-	100	ns
Storage Time	$t_s$		-	-	70	ns
Fall Time	$t_f$		-	-	50	ns

Note 2. Pulse Test: Pulse Width  $\leq 300\mu\text{s}$ , Duty Cycle  $\leq 2\%$ .

